## SUPPLEMENTARY INFORMATION Effects of hole transport layer on the performance of sky-blue Dion-Jacobson perovskite light-emitting diodes

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Figure S1. PL spectra of perovskites with 45% DDABr<sub>2</sub> and different content of MDABr<sub>2</sub>.



**Figure S2.** SEM images of DDA-MDA perovskite on different HTLs: a) 2PACz, b) 2PACz/PVK and c) 2PACz/PVK/TSPO1.



**Figure S3**. Space-charge-limited current (SCLC) measurement of electron-only device with the architecture ITO/SnO<sub>2</sub>/PEIE/DDA-MDA perovskite/TPBi/Liq/Al.



**Figure S4**. SCLC measurement of DDA-MDA perovskite-based LED devices with different HTLs: a) 2PACz, b) 2PACz/PVK, and c) 2PACz/PVK/TSPO1. Device architecture was ITO/HTL/Perovskite/CBP/MoO<sub>x</sub>/Al, where CBP denotes 4,4'-bis(N-carbazolyl)-1,1'-biphenyl.



Figure S5. TRPL decay curves of perovskite films on different HTLs.

**Table S1.** Fitting parameters of TRPL curves to exponential decay model described as  $I(t) = \sum_{i}^{n} A_{i} exp(-t/\tau_{i})$ , with average decay time calculated as  $\tau_{avg} = \sum_{i}^{n} A_{i} \tau_{i} / \sum_{i}^{n} A_{i}$ .

HTL	A <sub>1</sub>	$\tau_1$ (ns)	A <sub>2</sub>	$\tau_2(ns)$	$\tau_{avg}(ns)$
2PACz	0.94	1.52	-	-	1.52
2PACz/PVK	0.75	1.16	0.23	4.00	1.83
2PACz/PVK/TSPO1	0.60	1.18	0.36	4.26	2.34



Figure S6. The luminance of devices as a function of time at a fixed current bias of 0.2 mA (corresponding to initial luminance in the range 90-99  $cd/m^2$ ).



**Figure S7**. a) Fermi edge of 2PACz and 2PACz/PVSK, b) Fermi edge of 2PACz, 2PACz/PVK and 2PACz/PVK/PVSK, c) Fermi edge of 2PACz, 2PACz/PVK, 2PACz/PVK/TSPO1 and 2PACz/PVK/TSPO1/PVSK, d) SE Cut-off of 2PACz and 2PACz/PVSK, e) SE Cut-off of 2PACz, 2PACz/PVK and 2PACz/PVK/PVSK and f) SE Cut-off of 2PACz, 2PACz/PVK, 2PACz/PVK/TSPO1 and 2PACz/PVK/TSPO1/PVSK.